CDx4HC4040、CDx4HCT4040 高速 CMOS ロジック、12 段バイナリ・カウンタ

1 特長

- 完全静的動作
- バッファ付き入力
- コモン・リセット
- 負のエッジのパルス
- ファンアウト (全温度範囲にわたって)
  - 標準出力:10 個の LSTTL 負荷
  - バス・ドライバ出力:15 個の LSTTL 負荷
- 広い動作温度範囲:-55℃～125℃
- 平衡のとれた伝搬遅延と遷移時間
- LSTTL ロジック IC に比べて消費電力を大幅削減
- HC タイプ
  - 2V～6V で動作
  - 優れたノイズ耐性:V_{CC} に対して N_{IL} = 30% (V_{CC} = 5V 時)
- HCT タイプ
  - 4.5V～5.5V で動作
  - LSTTL 入力ロジックと直接互換、V_{IL} = 0.8V (最大値)、V_{IH} = 2V (最小値)
  - CMOS 入力互換、V_{OL}、V_{OH} で I_I ≦ 1μA

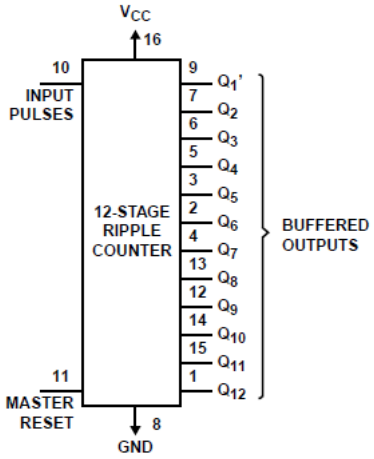
2 概要

'HC4040 および 'HCT4040 は、14 段リップルキャリー・バイナリ・カウンタです。すべてのカウンタ段は、コントローラ・フリップフロップです。段の状態は、各入力パルスの負のクロック遷移時に 1 カウント進み、MR ラインが High 電圧レベルになると、すべてのカウンタがゼロ状態にリセットされます。すべての入出力はバッファ付きです。

製品情報

部品番号	パッケージ (1)	本体サイズ (公称)
CD54HC4040	J (CDIP、16)	24.38mm × 6.92mm
CD54HCT4040	J (CDIP、16)	24.38mm × 6.92mm
CD74HC4040	D (SOIC、16)	9.90mm × 3.90mm
	N (PDIP、16)	19.31mm × 6.35mm
CD74HCT4040	D (SOIC、16)	9.90mm × 3.90mm
	N (PDIP、16)	19.31mm × 6.35mm

(1) 利用可能なパッケージについては、このデータシートの末尾にある注文情報を参照してください。



機能ブロック図

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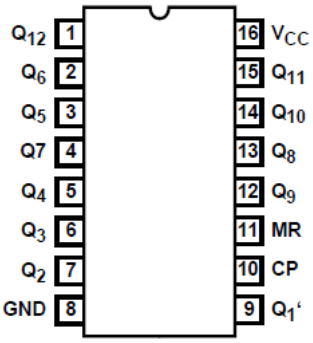
3 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision D (October 2003) to Revision E (July 2022)	Page
• 最新のデータシート規格を反映するように、文書全体の採番、書式設定、表、図、相互参照を更新	1

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4 Pin Configuration and Functions



J, D, or N package
16-Pin CDIP, SOIC, or PDIP
Top View

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		– 0.5	7	V
I_{IK}	Input clamp current(2)	(V_I < – 0.5 V or V_I > V_{CC} + 0.5 V)		± 20	mA
I_{OK}	Output clamp current(2)	(V_O < – 0.5 V or V_O > V_{CC} + 0.5 V)		± 20	mA
I_O	Output source or sink current per output pin	(V_O > – 0.5 V or V_{CC} + 0.5 V)		± 25	mA
	Continuous current through V_{CC} or GND			± 50	mA
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		– 65	150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 Recommended Operating Conditions(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range	HC types	2	6	V
		HCT types	4.5	5.5	
V_I, V_O	DC input or output voltage		0	V_{CC}	V
	Input rise and fall time	2 V		1000	ns
		4.5 V		500	
		6 V		400	
T_A	Temperature range		–55	125	℃

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

5.3 Thermal Information

THERMAL METRIC		D (SOIC) 16 PINS	N (PDIP) 16 PINS	NS (SOP) 16 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance(1)	73	67	64	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.

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5.4 Electrical Characteristics

PARAMETER		TEST CONDITIONS[1]	V_{CC} (V)	25℃			-40℃ to 85℃		-55℃ to 125℃		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
V_{IH}	High level input voltage		2	1.5			1.5		1.5		V
			4.5	3.15			3.15		3.15		
			6	4.2			4.2		4.2		
V_{IL}	Low level input voltage		2			0.5		0.5		0.5	V
			4.5			1.35		1.35		1.35	
			6			1.8		1.8		1.8	
V_{OH}	High level output voltage CMOS loads	I_{OH} = – 20 μA	2	1.9			1.9		1.9		V
		I_{OH} = – 20 μA	4.5	4.4			4.4		4.4		
		I_{OH} = – 20 μA	6	5.9			5.9		5.9		
	High level output voltage TTL loads	I_{OH} – 4 mA	4.5	3.98			3.84		3.7		V
		I_{OH} – 5.2 mA	6	5.48			5.34		5.2		
V_{OL}	Low level output voltage CMOS loads	I_{OL} = 20 μA	2			0.1		0.1		0.1	V
		I_{OL} = 20 μA	4.5			0.1		0.1		0.1	
		I_{OL} = 20 μA	6			0.1		0.1		0.1	
	Low level output voltage TTL loads	I_{OL} = 4 mA	4.5			0.26		0.33		0.4	V
		I_{OL} = 5.2 mA	6			0.26		0.33		0.4	
I_I	Input leakage current	V_{CC} or GND	6			±0.1		±1		±1	μA
I_{CC}	Supply current	V_{CC} or GND	6			8		80		160	μA
HCT TYPES											
V_{IH}	High level input voltage		4.5 to 5.5	2			2		2		V
V_{IL}	Low level input voltage		4.5 to 5.5			0.8		0.8		0.8	V
V_{OH}	High level output voltage CMOS loads	I_{OH} = – 20 μA	4.5	4.4			4.4		4.4		V
	High level output voltage TTL loads	I_{OH} = – 4 mA	4.5	3.98			3.84		3.7		V
V_{OL}	Low level output voltage CMOS loads	I_{OL} = 20 μA	4.5			0.1		0.1		0.1	V
	Low level output voltage TTL loads	I_{OL} = 4 mA	4.5			0.26		0.33		0.4	V
I_I	Input leakage current	V_{CC} and GND	5.5			±0.1		±1		±1	μA
I_{CC}	Supply current	V_{CC} or GND	5.5			8		80		160	μA
ΔI_{CC} [2]	Additional supply current per input pin	$\overline{MR}$ input held at V_{CC} -2.1	4.5 to 5.5		100	234		292.5		318.5	μA
		CP input held at V_{CC} – 2.1	4.5 to 5.5		100	180		225		245	μA

(1) $V_I = V_{IH}$ or V_{IL}, unless otherwise noted.
(2) For dual-supply systems theoretical worst case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8 mA.

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5.5 Prerequisite for Switching Characteristics

PARAMETER		V_{CC} (V)	25℃			-40℃ to 85℃		-55℃ to 125℃		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES										
f_{MAX}	Maximum input pulse frequency	2	6			5		4		MHz
		4.5	30			25		20		
		6	35			29		24		
t_W	Input pulse width	2	80			100		120		ns
		4.5	16			20		24		
		6	14			17		20		
t_{REM}	Reset removal time	2	50			65		75		ns
		4.5	10			13		15		
		6	9			11		13		
t_W	Reset pulse width	2	80			100		120		ns
		4.5	16			20		24		
		6	14			17		20		
HCT TYPES										
f_{MAX}	Maximum input pulse frequency	4.5	25			20		16		MHz
t_W	Input pulse width	4.5	20			25		30		ns
t_{REC}	Reset recovery time	4.5	10			13		15		ns
t_W	Reset pulse width	4.5	20			25		30		ns

5.6 Switching Characteristics

Input t_r, t_f = 6 ns. See Parameter Measurement Information

PARAMETER		TEST CONDITIONS	V_{CC} (V)	25℃			-40℃ to 85℃		-55℃ to 125℃		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
t_{PLH}, t_{PHL}	Propagation delay time CP to Q1' Output	C_L = 50 pF	2			140		175		210	ns
			4.5			28		35		42	
		C_L = 15 pF	5		11						
		C_L = 50 pF	6			24		30		36	
t_{PLH}, t_{PHL}	Qn to Q_n + 1	C_L = 50 pF	2			75		95		110	ns
			4.5			15		19		22	
		C_L = 15 pF	5		4						
		C_L = 50 pF	6			13		16		19	
t_{PLH}, t_{PHL}	MR to Q_n	C_L = 50 pF	2			170		215		255	ns
			4.5			34		43		51	
			5		14						
			6			29		37		43	
t_{TLH}, t_{THL}	Output transition time	C_L = 50 pF	2			75		95		110	ns
			4.5			15		19		22	
			6			13		16		19	
C_{IN}	Input capacitance	C_L = 50 pF				10		10		10	pF
C_{PD}	Power dissipation capacitance(1) (2)	C_L = 15 pF	5		40						pF
HCT TYPES											

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5.6 Switching Characteristics (continued)

Input t_r, t_f = 6 ns. See Parameter Measurement Information

PARAMETER		TEST CONDITIONS	V_{CC} (V)	25℃			-40℃ to 85℃		-55℃ to 125℃		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}, t_{PHL}	Propagation delay time CP to Q1' Output	C_L = 50 pF	4.5			40		50		60	ns
		C_L = 15 pF	5		17						
t_{PLH}, t_{PHL}	Qn to Q_n + 1	C_L = 50 pF	4.5			15		19		22	ns
		C_L = 15 pF	5		4						
t_{PLH}, t_{PHL}	MR to Q_n	C_L = 50 pF	4.5			40		50		60	ns
		C_L = 15 pF	5		17						
t_{TLH}, t_{THL}	Output transition	C_L = 50 pF	4.5			15		19		22	ns
C_{IN}	Input capacitance	C_L = 50 pF				10		10		10	pF
C_{PD}	Power dissipation capacitance(1) (2)	C_L = 15 pF	5		45						pF

(1) C_{PD} is used to determine the dynamic power consumption, per package.
(2) $P_D = V_{CC}{}^2 f_i(C_{PD} + C_L)$ where f_i = Input frequency, C_L = Output load capacitance, V_{CC} = Supply Voltage.

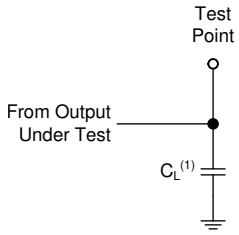
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6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_t < 6 ns.

For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C_L includes probe and test-fixture capacitance.

図 6-1. Load Circuit for Push-Pull Outputs

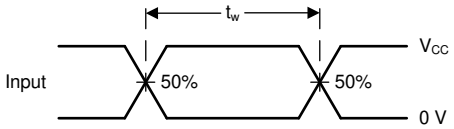


図 6-2. Voltage Waveforms, Standard CMOS Inputs Pulse Duration

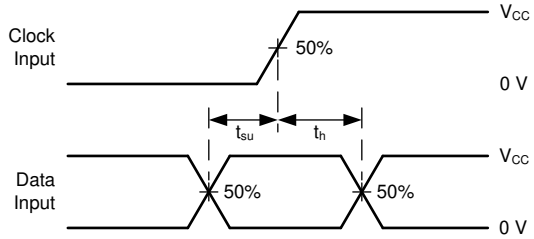
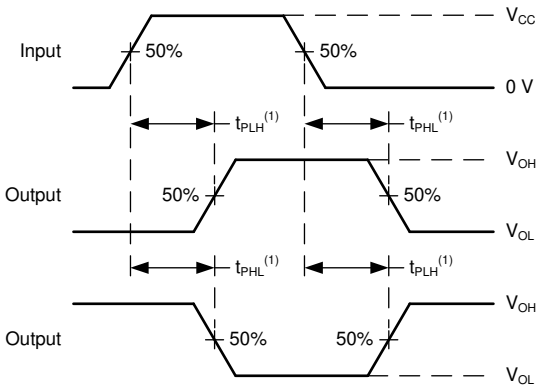
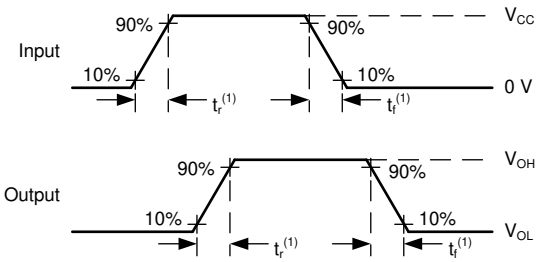


図 6-3. Voltage Waveforms, Standard CMOS Inputs Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

図 6-4. Voltage Waveforms, Propagation Delays for Standard CMOS Inputs



(1) The greater between t_r and t_f is the same as t_t.

図 6-5. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs

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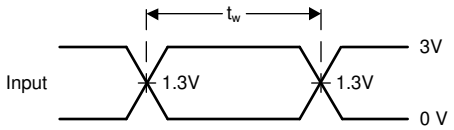


図 6-6. Voltage Waveforms, TTL-Compatible CMOS Inputs Pulse Duration

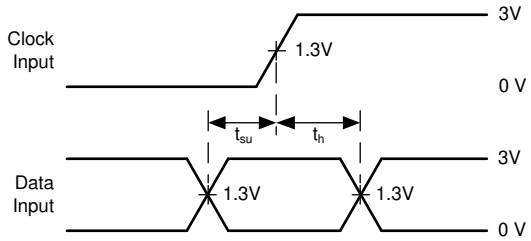
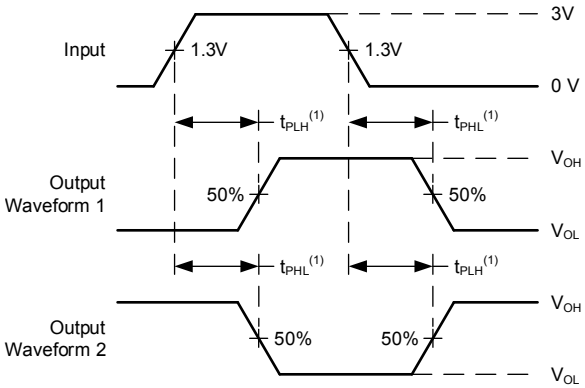


図 6-7. Voltage Waveforms, TTL-Compatible CMOS Inputs Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd}.

図 6-8. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs

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7 Detailed Description

7.1 Overview

The ’HC4040 and ’HCT4040 are 14-stage ripple-carry binary counters. All counter stages are controller flipflops. The state of the stage advances one count on the negative clock transition of each input pulse; a high voltage level on the MR line resets all counters to their zero state. All inputs and outputs are buffered.

7.2 Functional Block Diagram

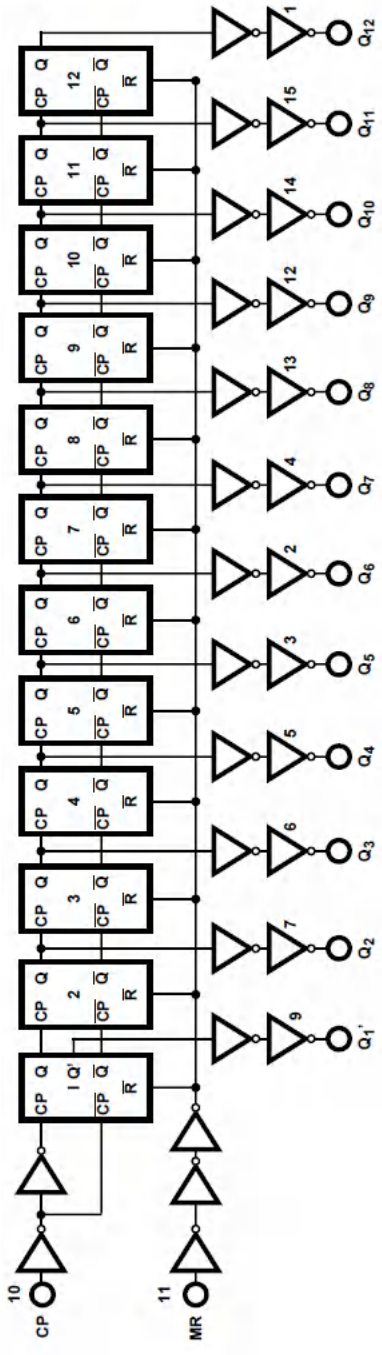


図 7-1. Functional Block Diagram

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7.3 Device Functional Modes

Function Table (Each Flip-Flop)(1)

CP COUNT	MR	OUTPUT STATE
↑	L	No Change
↓	L	Advance to Next State
X	H	All Outputs Are Low

(1) H = High voltage level, L = Low voltage level, X = Don't care, ↑ = Transition time from low to high level, ↓ = Transition from high to low.

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8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

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10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Documentation Support

10.1.1 Related Documentation

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 サポート・リソース

TI E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計で必要な支援を迅速に得ることができます。

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10.4 Trademarks

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10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-8994701MEA	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8994701ME A CD54HCT4040F3A
CD54HC4040F	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HC4040F
CD54HC4040F.A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HC4040F
CD54HC4040F3A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8500401EA CD54HC4040F3A
CD54HC4040F3A.A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8500401EA CD54HC4040F3A
CD54HCT4040F3A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8994701ME A CD54HCT4040F3A
CD54HCT4040F3A.A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8994701ME A CD54HCT4040F3A
CD74HC4040E	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4040E
CD74HC4040E.A	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4040E
CD74HC4040M	Obsolete	Production	SOIC (D) | 16	-	-	Call TI	Call TI	-55 to 125	HC4040M
CD74HC4040M96	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	HC4040M
CD74HC4040M96.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4040M
CD74HC4040M961G4	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4040M
CD74HC4040M961G4.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4040M
CD74HCT4040E	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT4040E
CD74HCT4040E.A	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT4040E
CD74HCT4040M	Obsolete	Production	SOIC (D) | 16	-	-	Call TI	Call TI	-55 to 125	HCT4040M
CD74HCT4040M96	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4040M
CD74HCT4040M96.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4040M

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC4040, CD54HCT4040, CD74HC4040, CD74HCT4040 :

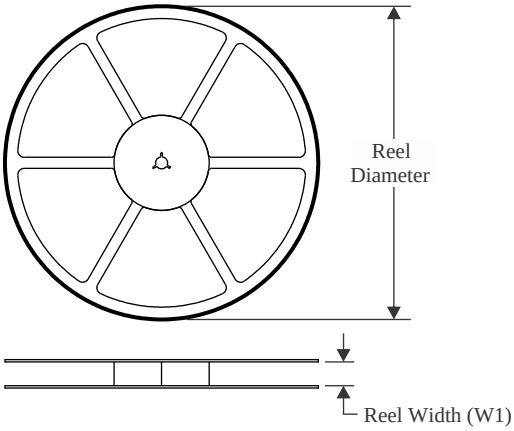
- Catalog : CD74HC4040, CD74HCT4040
- Military : CD54HC4040, CD54HCT4040

NOTE: Qualified Version Definitions:

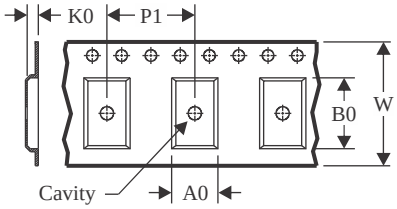
- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

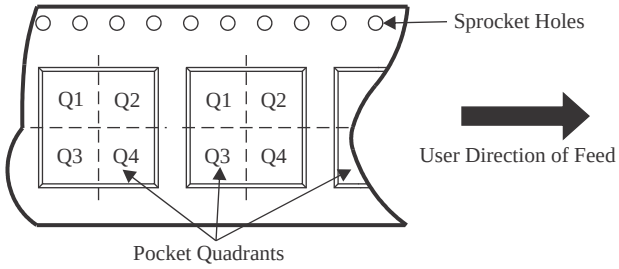


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

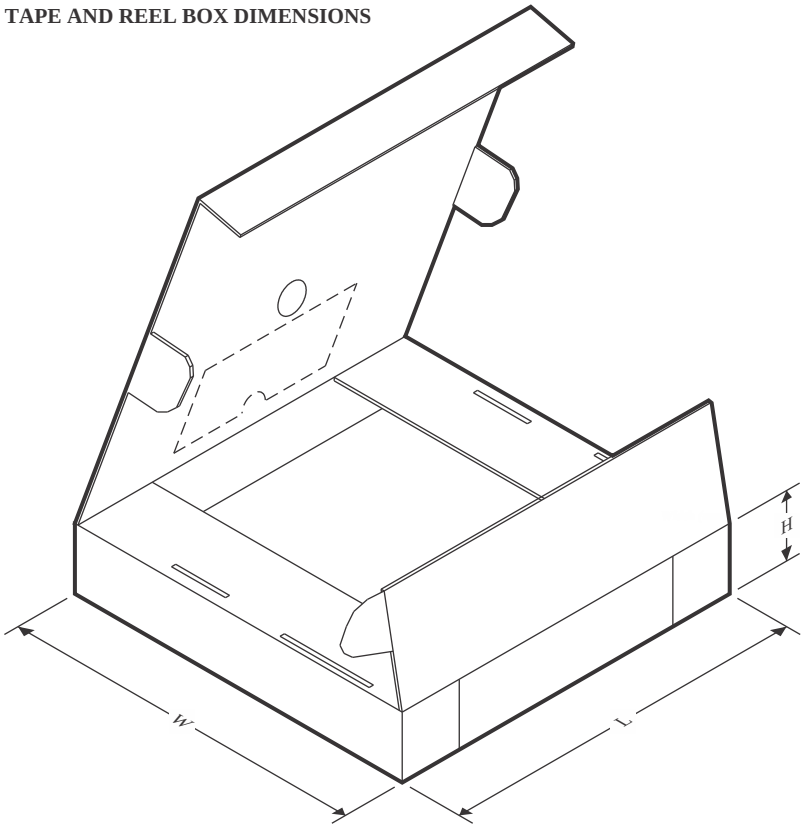
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4040M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4040M961G4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4040M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

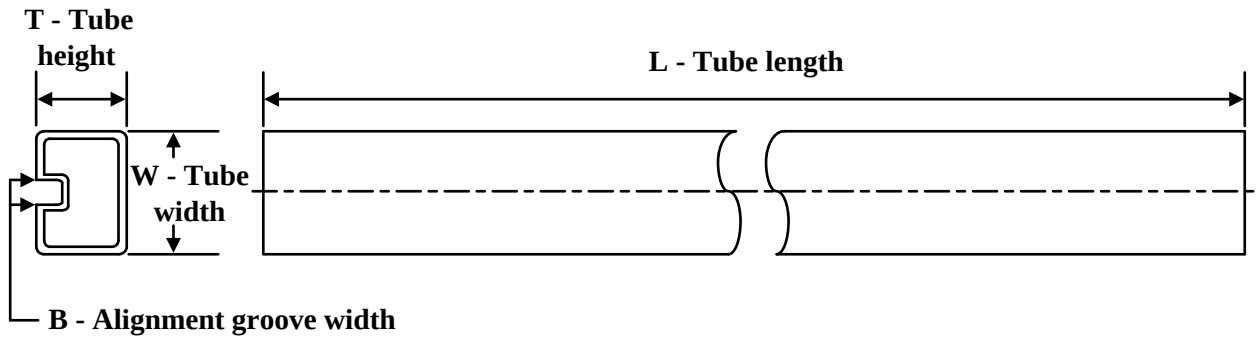
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4040M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HC4040M961G4	SOIC	D	16	2500	353.0	353.0	32.0
CD74HCT4040M96	SOIC	D	16	2500	353.0	353.0	32.0

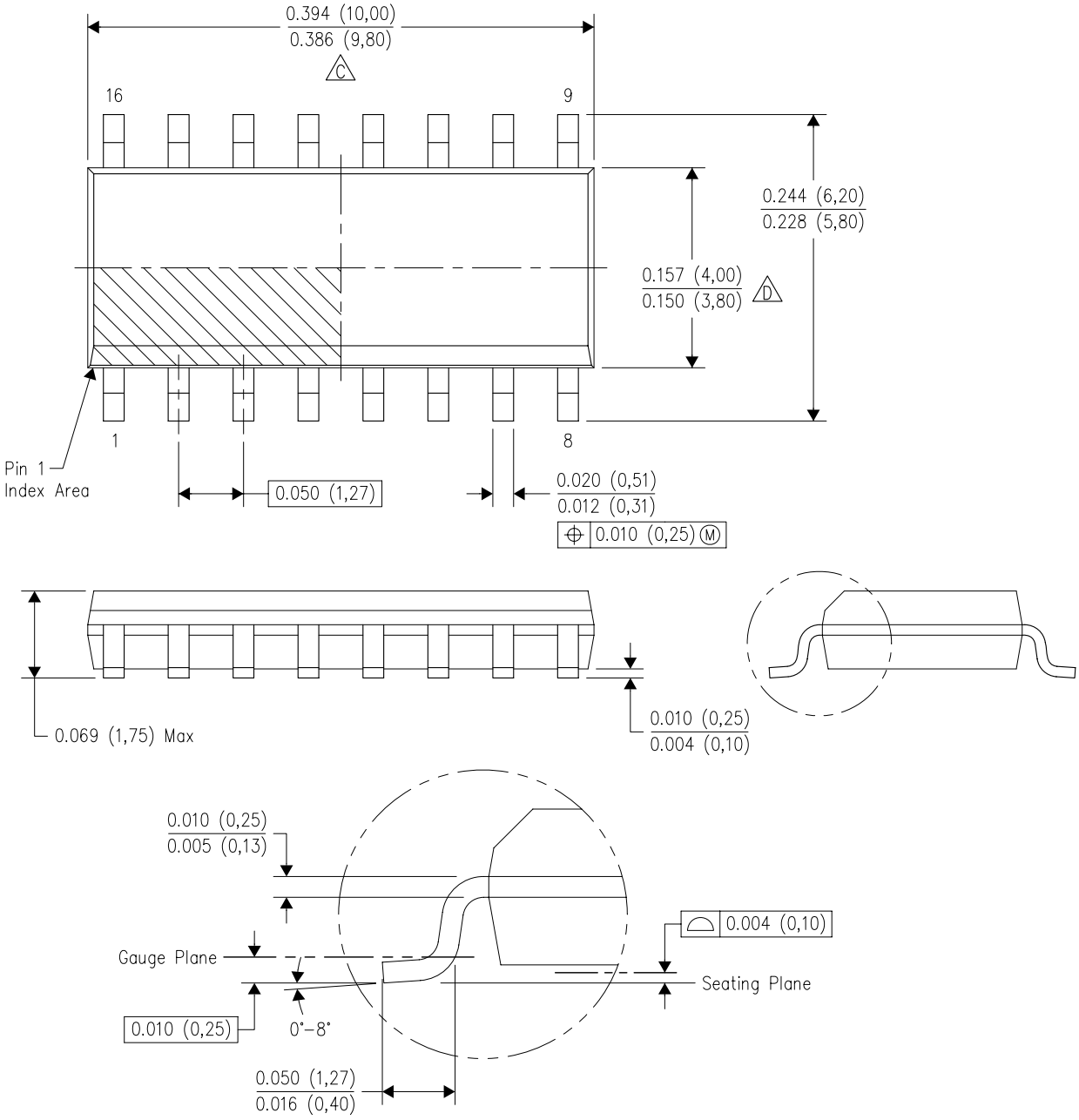
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC4040E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4040E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4040E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4040E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4040E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4040E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4040E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4040E.A	N	PDIP	16	25	506	13.97	11230	4.32

D (R–PDSO–G16) PLASTIC SMALL OUTLINE

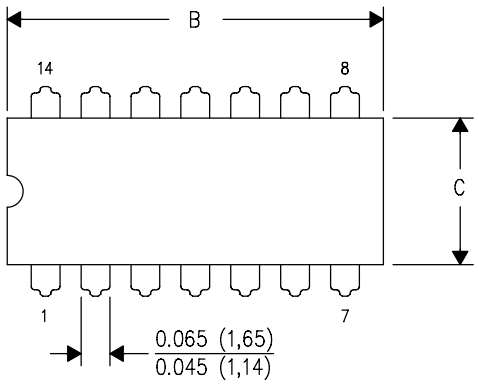


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

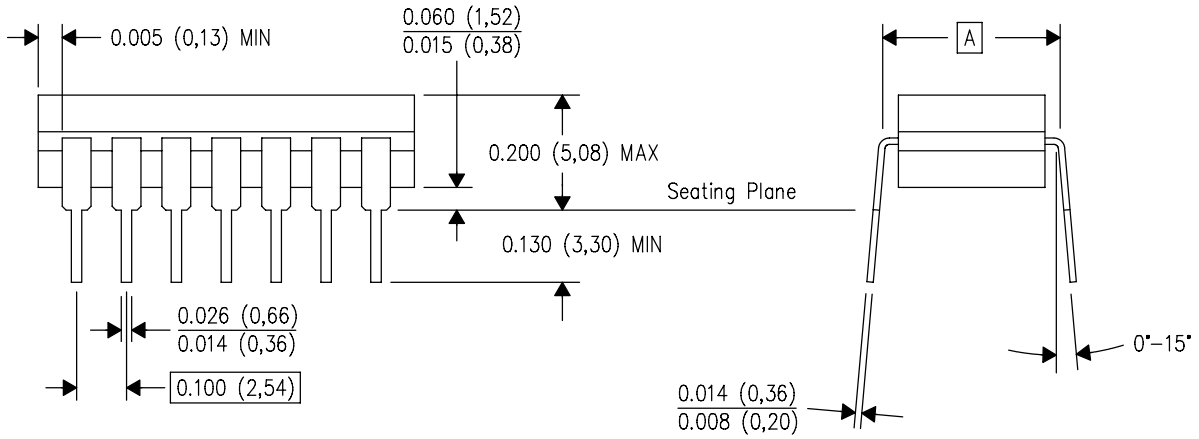
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



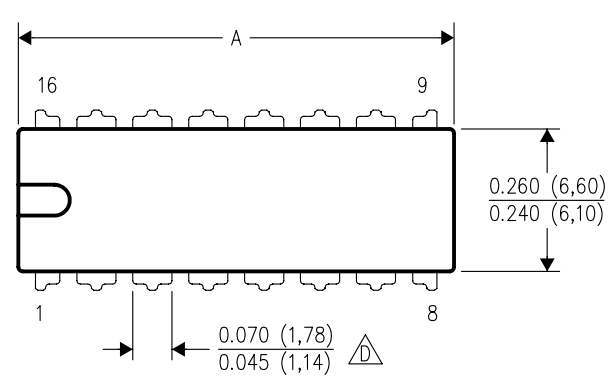
4040083/F 03/03

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

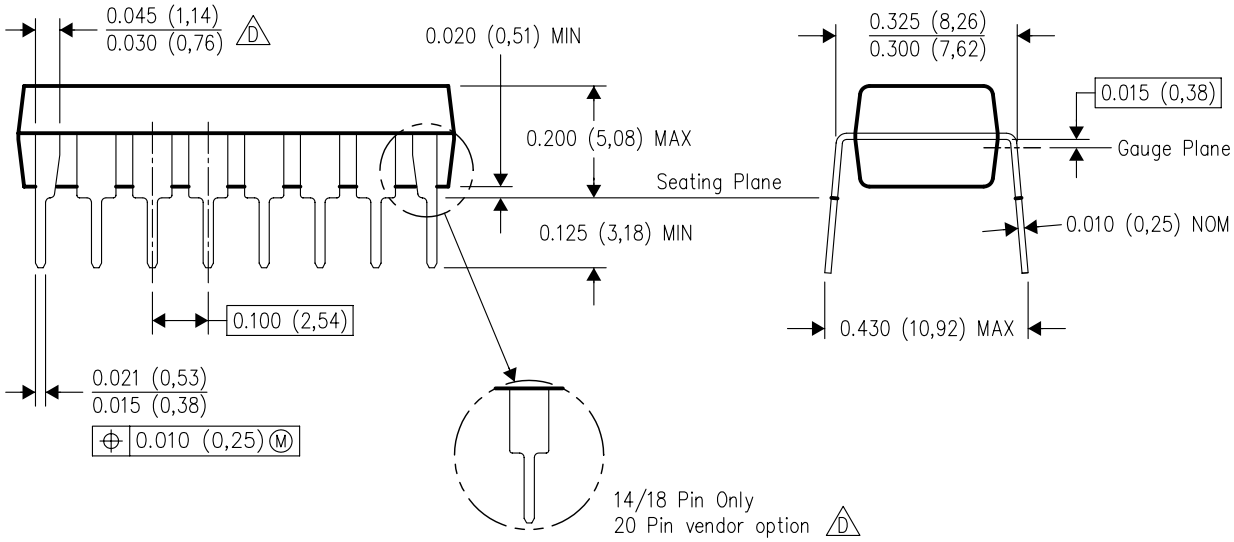
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

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